

### DESCRIPTION

These devices are monolithic timing circuits capable of producing accurate time delays or oscillation. In the time delay mode of operation, the timed interval is controlled by a single external resistor and capacitor network. In the astable mode of operation, the frequency and duty cycle may be independently controlled with two external resistors and a single external capacitor.

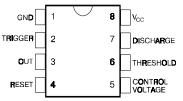
### **FEATURES**

- Timing from Microseconds to Hours
- Astable or Monostable Operation
- Adjustable Duty Cycle
- TTL Compatible Output Can Sink or Source Up to 200 mA
- Temperature Stability of 0.005% per °C
- Direct Replacement for Signetics NE555 Timer

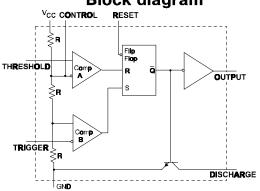
### **APPLICATIONS**

- Precision timing
- Pulse generation
- Sequential timing
- Time delay generation
- Pulse width modulation
- Pulse position modulation
- Missing pulse detector

# Pin Configuration (TOP VIEW)



### **Block diagram**



RESET can override TRIGGER, which can override THRESHOLD

# Absolute Maximum Ratings (T<sub>A</sub>=25°C, unless otherwise specified)

| PARAMETER   | MIN | MAX      | UNITS |
|---|-----|----------|-------|
| Supply Voltage, V <sub>CC</sub>                       | 4.5 | 16       | V     |
| Input Voltage (control, reset, threshold and trigger) |     | $V_{CC}$ |       |
| Output Current, I <sub>0</sub>                        |     | ±200     | mA    |
| Operating Free-Air Temperature, T <sub>A</sub>        |     | 70       | ∘C    |
| Storage Temperature Range, T <sub>STG</sub>           | -65 | +150     |       |

### **Function Table**

| RESET | TRIGGER VOLTAGE *     | THRESHOLD VOLTAGE *   | OUTPUT                    | DISCHARGE SWITCH |  |  |  |  |
|-------|-----------------------|-----------------------|---------------------------|------------------|--|--|--|--|
| Low   | Irrelevant            | Irrelevant            | Low                       | On               |  |  |  |  |
| High  | < 1/3 V <sub>CC</sub> | High                  | High                      | Off              |  |  |  |  |
| High  | > 1/3 V <sub>CC</sub> | > 2/3 V <sub>CC</sub> | Low                       | On               |  |  |  |  |
| High  | > 1/3 V <sub>CC</sub> | < 2/3 Vcc             | As previously established |                  |  |  |  |  |

<sup>\*</sup> Voltage levels shown are nominal

## TYPICAL APPLICATION DATA

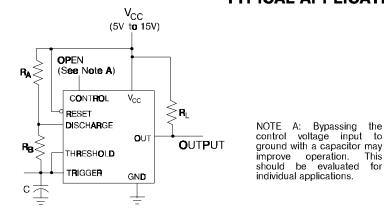


Fig. 1 Circuit for astable operation

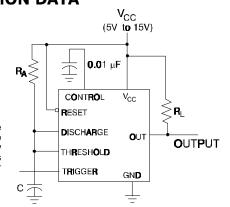


Fig. 2 Circuit for monostable operation



### Electrical characteristics (T<sub>A</sub>=25°C, V<sub>CC</sub>=+5V to +15V, unless otherwise specified)

| PARAMETER                      |                       | TEST CONDITIONS (see Note 2) |   | MIN   | TYP  | MAX  | UNITS   |
|--------------------------------|-----------------------|------------------------------|---|-------|------|------|---------|
| Operating Supply Voltage Ran   | ge                    | (555 : 1515 = )              |   | 4.5   |      | 16   | V       |
| Threshold Voltage Level        |                       | V <sub>CC</sub> =15V         |   | 8.8   | 10   | 11.2 | V       |
|                                |                       | $V_{CC}=5V$                  |   | 2.4   | 3.3  | 4.2  |         |
| Threshold Current (see Note 1) |                       | (see Note 1)                 |   |       | 30   | 250  | nA      |
| Trigger Voltage Level          |                       | V <sub>CC</sub> =15V         |   | 4.5   | 5    | 5.6  | V       |
|                                |                       | $V_{CC}=5V$                  |   | 1.1   | 1.67 | 2.2  |         |
| Trigger Current                |                       | Trigger at 0V                |   |       | 0.5  | 2    | μΑ      |
| Reset Voltage Level            |                       |                              |   | 0.3   | 0.7  | 1    | V       |
| Reset Current                  |                       | Reset at V <sub>CC</sub>     |   |       | 0.1  | 0.4  | mA      |
|                                |                       | Reset at 0V                  |   |       | -0.4 | -1.5 |         |
| Discharge Leakage Current      |                       |                              |   |       | 20   | 100  | nA      |
| Control Voltage Level          |                       | V <sub>CC</sub> =15V         |   | 9     | 10   | 11   | V       |
|                                |                       | V <sub>CC</sub> =5V          | -   | 2.6   | 3.3  | 4    |         |
| Low-level Output Voltage       |                       | V <sub>CC</sub> =15V         | I <sub>OL</sub> =10mA                       |       | 0.1  | 0.25 |         |
|                                |                       |                              | I <sub>OL</sub> =50mA                       |       | 0.4  | 0.75 |         |
|                                |                       |                              | I <sub>OI</sub> =100mA                      |       | 2    | 2.5  |         |
|                                |                       |                              | I <sub>OI</sub> =200mA                      |       | 2.5  |      |         |
|                                |                       | V <sub>CC</sub> =5V          | I <sub>OL</sub> =5mA                        |       | 0.25 | 0.35 |         |
|                                |                       |                              | I <sub>OL</sub> =8mA                        |       | 0.3  | 0.4  |         |
| High-level Output Voltage      |                       | V <sub>CC</sub> =15V         | l <sub>OI</sub> =-100mA                     | 12.75 | 13.3 |      |         |
|                                |                       |                              | I <sub>OI</sub> =-200mA                     |       | 12.5 |      |         |
|                                |                       | V <sub>CC</sub> =5V          | l <sub>OL</sub> =-100mA                     | 2.75  | 3.3  |      |         |
| Supply Current                 |                       | Output Low,                  | V <sub>CC</sub> =15V<br>V <sub>CC</sub> =5V |       | 10   | 15   | mA      |
|                                |                       | No Load                      | V <sub>CC</sub> =5V                         |       | 3    | 6    |         |
|                                |                       | Output High,                 | V <sub>CC</sub> =15V                        |       | 9    | 13   |         |
|                                |                       | No Load                      | V <sub>CC</sub> =5V                         |       | 2    | 5    |         |
|                                | nostable<br>e Note 4) | T <sub>A</sub> =25°C         |   |       | 1    | 3    | %       |
|                                | able<br>e Note 5)     |                              |   |       | 5    | 13   |         |
|                                | nostable              | T <sub>A</sub> =MIN to MAX   |   |       | 50   | 150  | ppm /°C |
| •                              | able                  |                              |   |       | 150  | 500  | ' ' ' - |
|                                | nostable              | T <sub>A</sub> =25°C         |   |       | 0.1  | 0.5  | %/V     |
|                                | able                  | 1                            |   |       | 0.3  | 1    |         |
| Output Pulse Rise Time         |                       | $C_{l} = 15pF, T_{A} = 1$    | 25°C  |       | 100  | 300  | ns      |
| Output Pulse Fall Time         |                       |                              |   |       | 100  | 300  | 110     |

#### Notes:

- 1. This parameter influences the maximum value of the timing resistors  $R_A$  and  $R_B$  in the circuit on Fig 1. For example, when  $V_{CC}$ =5V, the maximum value is  $R=R_A+R_B=3.4~M\Omega$ , and  $V_{CC}=15V$ , the maximum value is 10  $M\Omega$ .
- 2. For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
- 3. Timing interval error is defined as the difference between the measured value and the average value of a random sample from each process run.
- 4. Values specified are for a device in a monostable circuit similar to Fig. 2, with component values as follow:  $R_A=2K\Omega$  to 100  $K\Omega$ ,  $C=0.1\mu F$ .
- 5. Values specified are for a device in an astable circuit similar to Fig. 1, with component values as follow:  $R_A$ ,  $R_B$ =1 K $\Omega$  to 100 K $\Omega$ , C=0.1 $\mu$ F.